

Unveiling pressurized bulk superconductivity in a trilayer nickelate $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal

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The discovery of superconductivity in pressurized Ruddlesden-Popper (RP) nickelates has provided new perspectives on the mechanism of high-temperature superconductivity. Up to now, most experiments concentrated on the lanthanum-related RP phase, so the discovery of new superconducting RP nickelates is highly desirable to reveal their generality. Here we report the observation of superconductivity in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals above 10 GPa, achieving a maximum T_c of 39 K without saturation, significantly exceeding the value of 25–30 K of $\text{La}_4\text{Ni}_3\text{O}_{10}$. Ultrasensitive magnetic susceptibility measurements under high pressure indicate bulk superconductivity with appreciable superconducting volume fractions. Unlike $\text{La}_4\text{Ni}_3\text{O}_{10}$, the electronic structure of the high-pressure phase of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ exhibits a dramatic metallization of the σ -bonding band consisting of three d_{z^2} orbitals and van Hove singularity of coupled bands of $d_{x^2-y^2}$ orbitals near the Fermi level, similar to $\text{La}_3\text{Ni}_2\text{O}_7$. These findings reveal some generic features of both crystal and electronic structures for high-temperature superconductivity in nickelates and multi-layer cuprates.

superconductivity, high pressure, phase transition

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1 Introduction

Superconductors with high superconducting transition temperatures (T_c) remain a long-sought goal within the field of condensed-matter physics. In addition to cuprates [1–5] and hydrides [6–10], $\text{La}_3\text{Ni}_2\text{O}_7$ is one of the few superconductors with T_c above the liquid nitrogen temperature [11], which has opened up the era of nickel-based high-temperature superconductivity [12–31]. The recent observation of superconductivity at 82.5 K was reported in a Pr-doped $\text{La}_2\text{PrNi}_2\text{O}_7$ polycrystal under high pressure, accompanied by distinct diamagnetic signals [13]. The introduction of Pr has not only promoted the value of T_c but also significantly enhanced the superconducting phase purity. However, increasing the doping concentration of rare-earth elements in $\text{La}_{3-x}\text{Pr}_x\text{Ni}_2\text{O}_7$ remains experimentally challenging. Fortunately, the trilayer Ruddlesden-Popper (RP) nickelates $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ can be synthesized with high quality due to its efficient suppression of the intergrowth of different Ruddlesden-Popper phases during Pr substitution for La [32]. In 2020, the exploration of Pr-based nickel oxides was initiated with the successful growth of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals under oxygen pressure of 140 bar [33,34]. A distinctly anisotropic behavior between in-plane and out-of-plane was ascribed as well [33]. Synchrotron X-ray diffraction (XRD) and neutron diffraction results identify and characterize the intertwined charge- and spin-density waves (CDW and SDW) on the Ni sublattice in $R_4\text{Ni}_3\text{O}_{10}$ ($R = \text{La}, \text{Pr}$) [34,35].

Inspired by the above work, a question arises naturally: is it possible to achieve high-temperature superconductivity in Pr-based trilayer RP nickelates? To address this, we synthesized single crystals using an optical-image floating zone furnace. The characterization of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ in ambient conditions confirmed its high quality. A series of transport measurements under high pressure was carried out with solid-, liquid-, and gas-state pressure-transmitting media (PTMs). It demonstrated that the subtle high-pressure structural phase of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ necessitates an exceptionally high degree of pressure hydrostaticity. The density wave (DW) in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal was suppressed by pressure, and subsequently zero resistance emerges at ~ 30 GPa with Helium as PTM. Within the scope of our research, a maximum and unsaturated T_c of 39 K was achieved. A strong diamagnetic response confirmed the superconductivity of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$, yielding a superconducting volume fraction exceeding 80%. Concurrently, a structural phase transition from monoclinic to tetragonal structure occurred. Assessing

the evolution of pressure-induced NiO_6 octahedral configuration, which is enabled by synchrotron X-ray diffraction measurements under high pressure and low temperature $T = 16$ K, supports the meticulous depiction of electronic structure under high pressure. The established correlation between crystal structure and electronic structure in trilayer nickelates is crucial for elucidating the superconducting mechanism of nickelates and designing novel high-temperature superconductivity materials.

2 Results

$\text{Pr}_4\text{Ni}_3\text{O}_{10}$ is a member of the Ruddlesden-Popper trilayer rare-earth-nickelates, which is constructed by stacking of perovskite (PrNiO_3)₃ blocks and rock salt PrO layers along the c axis (Figure 1(a)). It crystallizes in the space group $P2_1/a$ with distorted NiO_6 octahedra. As reported, $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ nominally contains $\text{Ni}^{2+}/\text{Ni}^{3+}$, with an average valence state of +2.67 [34], which gives rise to strongly coupled electronic and magnetic phases. The $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal was successfully grown using an optical floating zone furnace under an oxygen pressure of 140–150 bar [33,34]. Figure 1(b) shows the XRD peaks from the ab plane of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals at room temperature. All peaks can be well indexed to the (00 l) reflections of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$. The compositions derived from energy dispersive spectroscopy (EDS) measurement reveal an atomic ratio of Pr:Ni = 4:3.09 (Figure S1(c)). The thermogravimetric analysis (TGA) data revealed that the oxygen content of the obtained crystal is about 9.99 (Figure S1(d)). The XRD, EDS, and TGA results collectively confirm the high quality of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals.

The temperature-dependent resistivity of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal is depicted in Figure 1(c). The resistivity decreases with decreasing temperature, displaying a metallic behavior. A distinct step-like kink is observed at around 156 K. This anomaly resembles the situation in $\text{La}_4\text{Ni}_3\text{O}_{10}$, suggesting the emergence of a DW state, as previously demonstrated in neutron diffraction experiments [36]. The heat capacity of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ is illustrated in Figure 1(d), where a sharp peak at 156 K indicates a DW phase transition. The anomaly below 10 K could be attributed to a magnetic ordering from 4 f -electrons of Pr ions [37].

The temperature-dependent resistance measurements of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ under high pressure were carried out with various PTMs. The DW suppression and subsequent metallization were clearly observed under increasing pressure using dif-

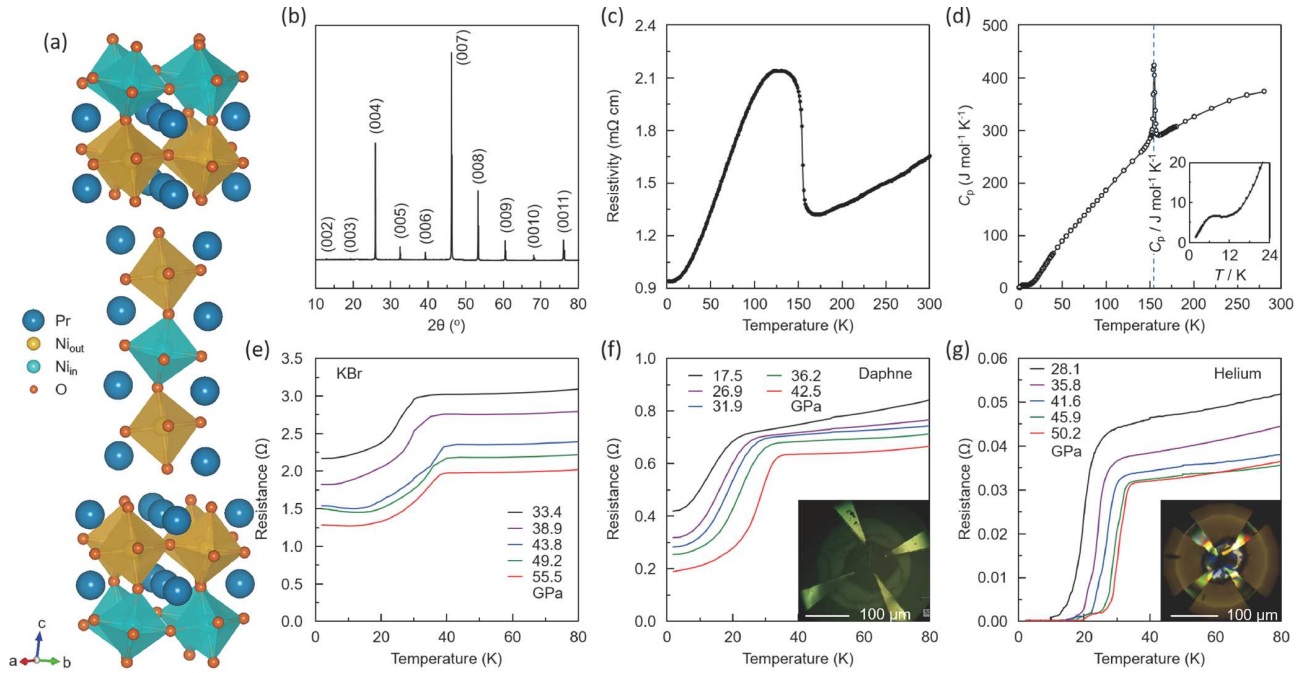


Figure 1 (Color online) Characterization of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ at ambient pressure and temperature-dependent resistances under various pressures. (a) Crystal structure of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$. (b) The room temperature XRD peaks from the ab plane of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal. (c) Temperature dependence of ab -plane resistivity $\rho(T)$ of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal. (d) The heat capacity C_p of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystal, and the inset is the enlarged heat capacity C_p at low temperatures. (e) Enlarged $R(T)$ curves in the vicinity of the superconducting transition with KBr as PTM. (f) Enlarged electrical resistance $R(T)$ of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ under different pressures with Daphne 7373 as PTM. The inset is a photograph of the electrodes used for high-pressure resistance measurements. (g) Enlarged $R(T)$ curves in the vicinity of the superconducting transition with Helium as PTM. The inset is the photograph of the electrodes used for high-pressure resistance measurements with Helium as PTM.

ferent PTMs, including no PTM, solid KBr, and liquid Daphne 7373 (Figure S2). Apparent drops in resistance (Figure 1(e) and (f)) were observed at ~ 20 GPa, however, the zero-resistance state was not achieved in any PTM cases. Due to the extreme sensitivity of superconducting properties of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ to pressure conditions, we employed Helium gas as the PTM to further improve the hydrostatic environment. As shown in Figure 1(g), the resistance of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ exhibited metallic behavior with the pressure over 28.1 GPa and the resistance decreased as pressure increased. An obvious decrease in resistance emerged below 20 K at 28.1 GPa, and as the pressure increased, it became more pronounced. At 35.8 GPa, the resistance $R(T)$ reached to zero around 15 K with an onset temperature of 26 K.

Moreover, we performed electrical resistance measurements under various magnetic fields at 50.2 GPa with Helium as PTM. As illustrated in Figure 2(a), the resistance drop was progressively suppressed under external magnetic fields, and is shifted to approximately 29 K at 7 T. Then we estimated the upper critical field $\mu_0 H_{c2}(T)$ by fitting it with the empirical Ginzburg-Landau formula $\mu_0 H_{c2}(T) = \mu_0 H_{c2}(0)(1 - t^2)/(1 + t^2)$, where $t = T/T_c$ (Figure 2(b)). The fitted zero-temperature upper critical field $\mu_0 H_{c2}(0)$ of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$, derived from the 90% resistance of the normal state around T_c , reached 49.4 T at 50.2 GPa. It should be

noted that the $\mu_0 H_{c2}(0)$ obtained exceeds the values reported for $\text{La}_4\text{Ni}_3\text{O}_{10}$, below the Pauli paramagnetic limit $H_p = 1.84T_c$. According to the relationship $\mu_0 H_{c2} = \Phi_0/(2\pi\xi^2)$, where $\Phi_0 = 2.07 \times 10^{-15}$ Wb, the Ginzburg-Landau coherence length $\xi_{\text{GL}}(0)$ is given by 2.58 nm at 50.2 GPa.

To further determine the nature of the pressure-induced zero-resistance state, we conducted ultrasensitive direct current (d.c.) magnetic susceptibility measurements under high pressures using a custom-built miniature beryllium-copper alloy DAC with Neon as PTM. Systematic analysis of the high-pressure d.c. susceptibility data revealed no obvious transition in either the zero-field-cooled (ZFC) or field-cooled (FC) modes at 18.6 GPa (Figure 2(c), Figure S3(a) and (d)). However, upon increasing the pressure to 42.2 GPa, a distinct diamagnetic transition was observed in the ZFC measurements (Figure 2(d), Figure S3(b) and (e)), which provides direct evidence of superconductivity under pressure. Thus, we estimated the maximum superconducting volume fraction, which exceeds 80% at 42.2 GPa, confirming the bulk superconductivity in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$. Upon further compression, the T_c evidenced by diamagnetic response rises from 23.6 K at 42.2 GPa to 29.9 K at 53.8 GPa (Figure 2(e), Figure S3(c) and (f)). Under these pressures, the superconducting transition temperature derived from magnetic

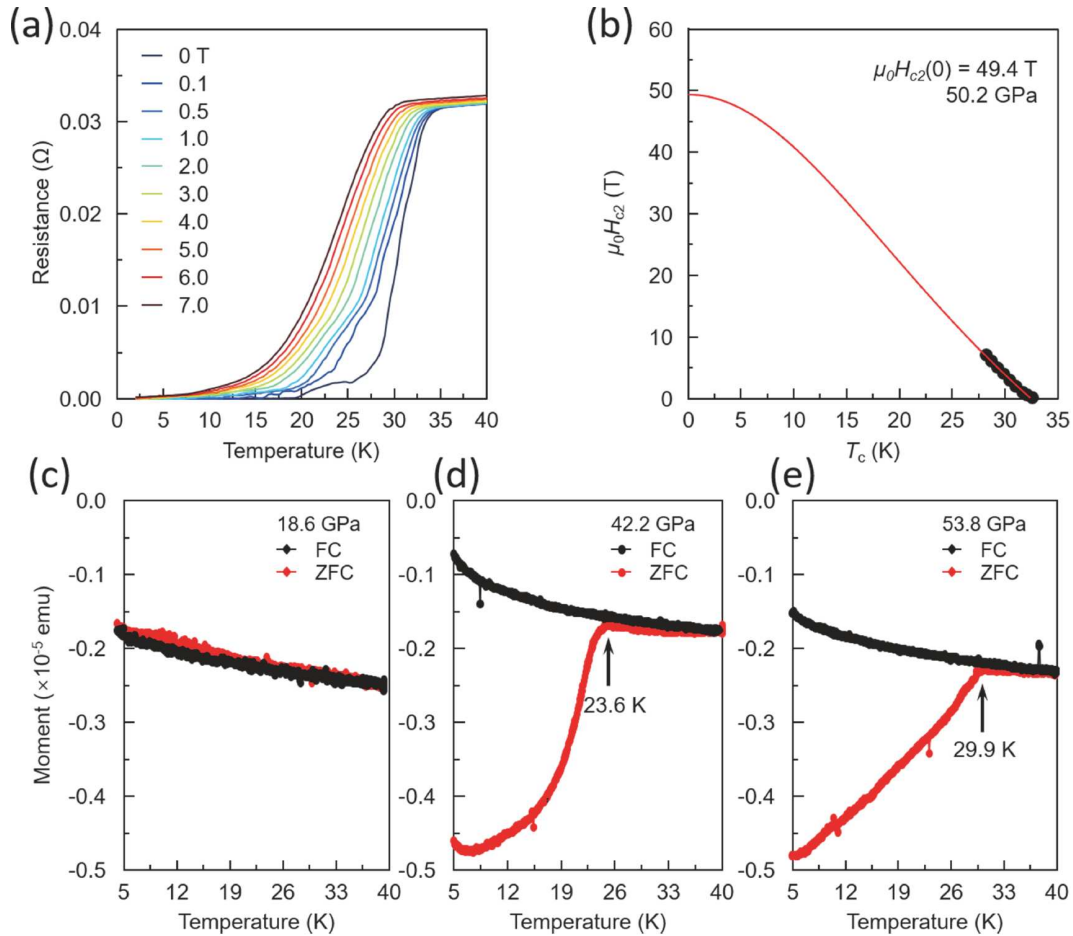


Figure 2 (Color online) Resistance of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ in magnetic field and d.c. susceptibilities under various pressures. (a) Field dependences of electrical resistance for sample $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ at 50.2 GPa with Helium as PTM. (b) Temperature dependence of the upper critical field $\mu_0 H_{c2}(T)$ at 50.2 GPa with Helium as PTM. Here, the values of T_c are determined at 90% of the normal state resistance just above the onset superconducting transition temperature. The red solid line represents the fits using the Ginzburg-Landau formula. (c)-(e) Temperature-dependent magnetization of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ under a magnetic field of 20 Oe using the ZFC and FC modes under 18.6, 42.2, and 53.8 GPa, respectively. Neon is used as PTM.

measurements is consistent with the results obtained from electrical transport measurements. This inter-method agreement provides robust corroboration of the pressure-induced superconducting state in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$.

After establishing the pressurized bulk superconductivity in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals, it is better to determine the crystal and electronic structures under the conditions that the samples become superconducting. So, we first performed *in situ* synchrotron XRD measurements on powdered $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ single crystals under various pressures at 16 K (Figure S4). The Rietveld refinement based on a monoclinic structure with $P2_1/a$ space group displays that the lattice parameters a and b are getting close to each other with increasing compression (Figure 3(b) and Figure S5(a)), the ratio of b/a drops dramatically and becomes metrically unity above ~ 30 GPa. The lattice parameters of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ under various pressures are smaller than those of $\text{La}_4\text{Ni}_3\text{O}_{10}$ [38], suggesting that the substitution of La with Pr caused more chemical pre-compression effect (Figure S6). In addition, a clear volume discontinuity was observed with a volume drop of 3.0% when

the pressure increases from 23.5 to 32.7 GPa (Figure S7). All these observations suggest pressure-induced structural transition towards a higher symmetry structure, which is similar to that observed in $\text{La}_4\text{Ni}_3\text{O}_{10}$ [36,39] (Figure S8). A typical Rietveld refinement based on tetragonal structure with space group $I4/mmm$ for the XRD pattern at 35.4 GPa and 16 K is shown in Figure S5(b). Notably, the difference between $P2_1/a$ and $I4/mmm$ phases is too subtle to distinguish the pressure-induced structural phase transition when the synchrotron XRD was investigated at room temperature (Figure S9).

As depicted in Figure 3(a), both of the low-pressure and high-pressure phases of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ contain two kinds of layers consisting of NiO_6 octahedra: one inner layer and two outer layers. We examined the length of Ni–O bonds along the c -axis and within the ab plane of the NiO_6 octahedra in both inner and outer layers. In the outer layers, the Ni–O bonds along the c -axis have a sudden decline after ~ 10 GPa in the $P2_1/a$ phase, which becomes a relatively constant ~ 1.83 Å in the $I4/mmm$ phase around 35 GPa (Figure 3(c)). The bond length in the ab plane also tends to ~ 1.83 Å in the

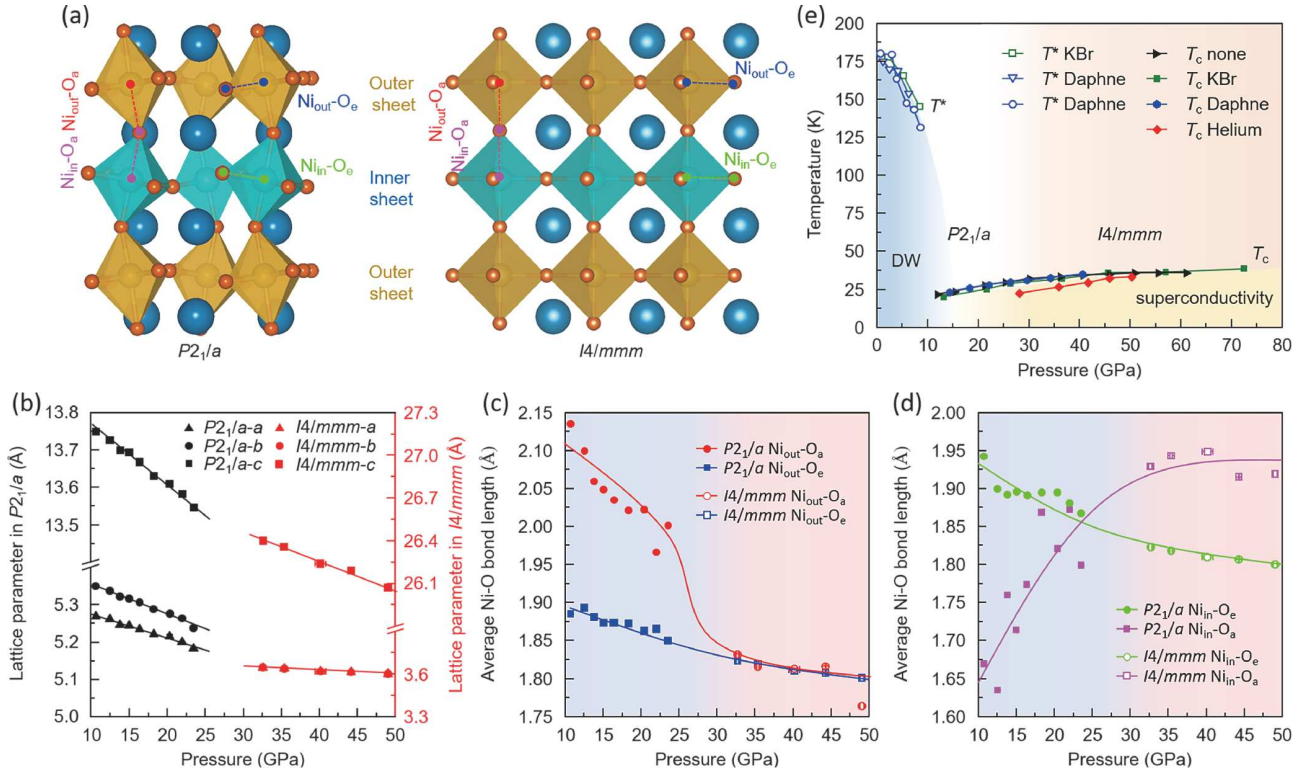


Figure 3 (Color online) Pressure-dependent crystal structure and phase diagram of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$. (a) The schematic of two different kinds of disordered NiO_6 octahedra for $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ in the low-pressure $P2_1/a$ phase and high-pressure $I4/mmm$ phase, respectively. (b) Pressure dependence of lattice parameters a , b , and c for $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ in the $P2_1/a$ phase (black) and a , c in $I4/mmm$ (red) phase extracted from the synchrotron XRD results obtained at 16 K. (c) Average Ni–O bond length on equatorial and axial plane of NiO_6 octahedra in the outer perovskite layers as a function of pressure at 16 K. (d) Average Ni–O bond length on equatorial and axial plane of NiO_6 octahedra in the inner perovskite layers as a function of pressure at 16 K. (e) Pressure dependence of the crystal structure, superconducting transition temperatures T_c and DW transition temperature T^* for $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ as the function of pressure.

$I4/mmm$ phase in the outer layers around 35 GPa, indicating the NiO_6 octahedra in the outer layers become more regular under high pressure. As for the inner layers, the Ni–O bonds along the c -axis have an abnormal incline in the $P2_1/a$ phase with increasing pressure, which converges to ~ 1.93 Å in the $I4/mmm$ phase around 35 GPa (Figure 3(d)). The Ni–O bonds in the ab plane of the inner layers share analogous features to those of outer layers, which become ~ 1.83 Å in the $I4/mmm$ phase around 35 GPa as well. This indicates the NiO_6 octahedra in the inner layers are less regular than those in outer layers. The population standard deviation σ_{JT} in these two phases, which is used to scale the degree of deviation from the mean value, also confirms the improvement of the regularity of the Ni–O octahedra after the structure phase transition (Figures S10 and S11). Therefore, the atomic environment becomes more similar in both inner and outer layers after the structural transition, which induces relatively drastic variation along the c -axis. Such a process could improve the symmetry of crystals, conducive to the pairing of the superconductivity.

Notably, NiO_6 octahedra tilt and rotate during the pressure-induced phase transition. Additionally, the oxygen positions gradually shift from off-center positions between $\text{Ni}_{\text{out}}\text{--Ni}_{\text{in}}$ centers towards their central positions. The resulting periodic

charge density distribution may account for the origin of the weak charge/magnetic order. Upon phase transition, the octahedral structure converges, and the oxygen positions approach the $\text{Ni}_{\text{out}}\text{--Ni}_{\text{in}}$ centers, leading to the DW disappearance. This is consistent with the DW suppression in electrical transport results under high pressure.

3 Discussion and conclusions

Based on the above electrical transport and structural results under pressure, the T - P phase diagram is summarized in Figure 3(e), where the data are included from high-pressure measurements using a DAC, both in the absence of a PTM and with PTMs including a solid (KBr), a liquid (Daphne 7373), and a gaseous medium (Helium). In the lower pressure region, $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ undergoes two transitions, forming the intertwined DW on the Ni sublattice and the magnetic order on the Pr sublattice. The DW state manifests as an anomaly in resistance, which is suppressed under pressure. A superconducting state emerges between 10–20 GPa. The value of T_c increases dramatically with pressure, and a maximum T_c of 39 K was obtained without saturation. The *in situ* high-pressure low-temperature XRD results indicate that

the structural transition is a prerequisite to trigger superconductivity in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$. Furthermore, the realignment of the NiO_6 octahedra and the chemical pre-compression by Pr atoms could be beneficial to the increase in T_c under high pressure.

To analyze the evolution of electronic structures of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ under external high pressure, we perform the calculation of density functional theory (DFT) methods for given typical pressures within the GGA+ U framework [40] based on Dudarev's method [41]. Here, the on-site Coulomb interaction among the Ni electrons is chosen as $U = 4$ eV, while the f -electronic states of Pr ions are pushed far away from the Fermi energy by using a sufficiently large value of U due to their nature of locality. As shown in Figure 4(a), we can see that both the $d_{x^2-y^2}$ and d_{z^2} bands mixed with oxygen p -orbitals. From the inequivalent inner- and outer-layer Ni sites, these bands exhibit distinguishable orbital contributions, intersect with Fermi level, and are strongly inter-hybridized with each other. These characteristics are robust under pressure. Due to the quantum confinement within the

trilayer structural complex, the $3d_{z^2}$ orbitals strongly interact via inter-layer apical oxygen along the c axis, forming three “molecular orbital bands”. The molecular orbital description can be demonstrated in terms of a Ni trimer coupled with a nearest neighbor hopping parameter $t_{\perp}$, giving rise to the bonding (B), anti-bonding (AB), and non-bonding (NB) states [42,43]:

$$\varepsilon_{z^2}^{\text{B}} = -\sqrt{2} t_{\perp}, \quad |\text{B}\rangle = 1/2(1, \sqrt{2}, 1), \quad (1)$$

$$\varepsilon_{z^2}^{\text{NB}} = 0, \quad |\text{NB}\rangle = 1/\sqrt{2}(1, 0, -1), \quad (2)$$

$$\varepsilon_{z^2}^{\text{AB}} = \sqrt{2} t_{\perp}, \quad |\text{AB}\rangle = 1/2(1, -\sqrt{2}, 1), \quad (3)$$

respectively. It can be seen that the B and AB states are formed by linear combinations of d_{z^2} orbitals from all three Ni layers with even parity, while the NB state exclusively originates from a mixture of d_{z^2} orbitals from two outer Ni sites with odd parity. This interlayer molecular orbital scenario applies to all structures before and after the pressure-induced phase transition, as clearly demonstrated in layer- and orbital-resolved band structures in Figure 4(a) and (c).

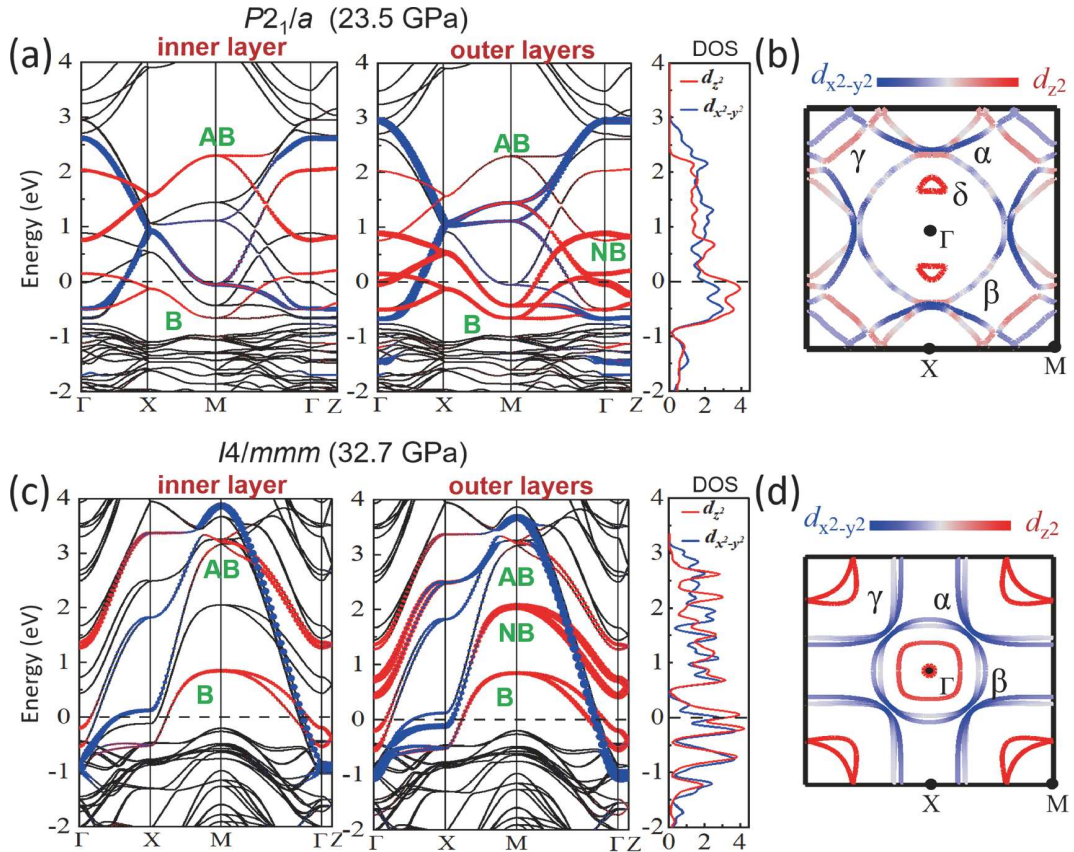


Figure 4 (Color online) Layer and orbital resolved non-magnetic electronic structures of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ at hydrostatic pressure 23.5 GPa (low-symmetry $P2_1/a$) and 32.7 GPa (high-symmetry $I4/mmm$). (a), (c) Band structures with highlighted d_{z^2} (in red) and $d_{x^2-y^2}$ (in blue) orbital characters for the Ni inner and outer layers. We label the Ni d_{z^2} bonding (B), non-bonding (NB), and anti-bonding (AB) bands within the molecular orbital description. The tetragonal setting is used for the high symmetry K point path. We adopt the notation of $d_{x^2-y^2}$ based on the local coordination of Ni–O octahedra, though monoclinic $P2_1/a$ structure is close to $\sqrt{2} \times \sqrt{2}$ supercell of the $I4/mmm$ structure with pronounced tilting and nearly 45° rotation of Ni–O octahedra. The corresponding total density of states for these orbitals is shown on the right. The Fermi level is marked by the horizontal dashed line. (b), (d) Fermi surfaces in the $k_z = 0$ plane with orbital-resolved α , β , and γ sheets.

Different from the d_{z^2} orbitals, the vertical interlayer coupling of the $d_{x^2-y^2}$ orbitals is much weaker, resulting in close energetics of $d_{x^2-y^2}$ bonding, non-bonding and anti-bonding bands.

Actually, a closer inspection can reveal that the Fermi surface of low-symmetry $P2_1/a$ phase comprises several sheets (Figure 4(b)): hole-like α and δ pockets located at the X point and near the Γ point, respectively, while the electron-like β and γ pockets center at the Γ and M points of the tetragonal Brillouin zone, respectively. Due to the monoclinic lattice distortion, the α , β , and γ pockets have mixed characters of e_g orbitals, while the δ pocket is predominantly in d_{z^2} character. With increasing pressure in the low-symmetry $P2_1/a$ phase, the band widths of both orbitals are increased, and the δ pocket is narrowed (Figure 4(a) and (b), Figure S12).

However, after the structural phase transition, the Fermi surface topology is significantly changed, and electronic structure exhibits many new features (Figure 4(c) and (d)). (1) The Fermi surface consisting of one hole-like α sheet with dominant $d_{x^2-y^2}$ character is centered at M point, while an electron-like β sheet with the mixed e_g orbital character is around the Γ point. (2) Another hole-like γ pocket featuring dominant d_{z^2} bonding bands sits around the M point, and extra electron pockets from the d_{z^2} bonding band emerging at Γ point cross the Fermi level. (3) The $d_{x^2-y^2}$ orbital bands exhibit the van Hove singularity at the X point with peaked density of states near the Fermi level (Figure 4(c)). Crucially, there is a dramatic change of the γ pocket from electron-like to hole-like with the onset of the structural phase transition.

Our electronic structure calculations based on experimentally determined low-temperature crystal structures provide an opportunity to compare band filling and Fermi

surface topology of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ with those of $\text{La}_4\text{Ni}_3\text{O}_{10}$ and $\text{La}_3\text{Ni}_2\text{O}_7$ superconducting phases. A formal valence count for $\text{La}_4\text{Ni}_3\text{O}_{10}$ and $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ renders a $\text{Ni}^{2.67+}$ state corresponding to an average $3d^{7.33}$ filling of the Ni 3d shell, while the valence count for $\text{La}_3\text{Ni}_2\text{O}_7$ gives a $\text{Ni}^{2.5+}$ state corresponding to an average $3d^{7.5}$ filling. Considering the fact that the large crystal field splits t_{2g} orbitals away from the Fermi level, only four (three) electrons are active in the e_g orbitals near the Fermi level for $\text{La}_4\text{Ni}_3\text{O}_{10}$ and $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ ($\text{La}_3\text{Ni}_2\text{O}_7$), respectively. The way to fill up these electrons in the e_g orbitals imposed by strong interlayer coupling of d_{z^2} orbitals may crucially affect the nature of superconductivity.

In Figure 5, we display the electronic energy levels of the nickel oxide complexes of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$, $\text{La}_4\text{Ni}_3\text{O}_{10}$, and $\text{La}_3\text{Ni}_2\text{O}_7$ within the interlayer molecular orbital scenario. In the $\text{La}_4\text{Ni}_3\text{O}_{10}$ case, four electrons of e_g orbitals occupy three different bands in the manner that the d_{z^2} bonding band just touches the Fermi surface (nearly fully filled), while the d_{z^2} non-bonding band and $d_{x^2-y^2}$ band cross the Fermi surface (partially filled), see Figure 5(a). In contrast, four electrons in $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ only occupy $d_{x^2-y^2}$ band (partially filled) and d_{z^2} bonding band (partially filled), as described in Figure 5 (b). A large proportion of electrons occupies $d_{x^2-y^2}$ band, leading to the enhanced metallization of the d_{z^2} bonding band with enlarged hole pockets centered at the M point. As a consequence, $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ has an equivalent downward shift in the Fermi energy as compared to $\text{La}_4\text{Ni}_3\text{O}_{10}$. More importantly, $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ has striking similarities with $\text{La}_3\text{Ni}_2\text{O}_7$, where the d_{z^2} bonding band slightly touches the Fermi level (nearly fully filled) and the $d_{x^2-y^2}$ band cross the Fermi surface (quarter-filled). Only $d_{x^2-y^2}$ and d_{z^2} bonding bands are active orbitals around the Fermi level, corresponding to a dramatic metallization of the σ -bonding band consisting of

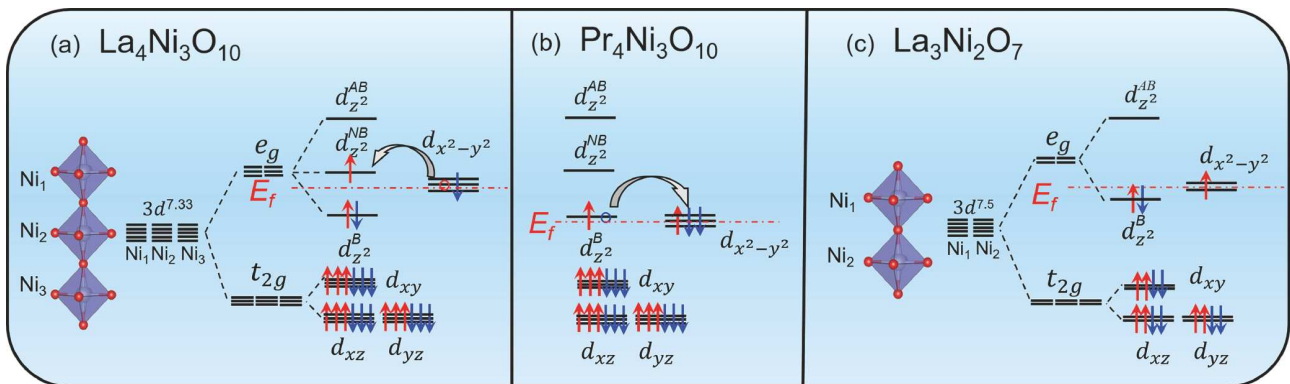


Figure 5 (Color online) Simplified electronic energy levels of the nickel oxide complexes showing the similarities and differences among various RP superconducting nickelates (a) $\text{La}_4\text{Ni}_3\text{O}_{10}$, (b) $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ and (c) $\text{La}_3\text{Ni}_2\text{O}_7$. Due to quantum confinement of the layered structure, the molecular orbital representation of the Ni trimer is more natural than individual atomic orbitals of each layer for the description of d_{z^2} orbital electrons. Band fillings are terminated by the Fermi level E_f , which are extracted from band structures. Charge transfer between $d_{x^2-y^2}$ and d_{z^2} orbitals due to the energy overlap is denoted by arrows. Notice that the energy splitting of $d_{x^2-y^2}$ orbital is less obvious as compared to the d_{z^2} orbitals, as the vertical interlayer coupling for $d_{x^2-y^2}$ orbitals is much smaller than that of d_{z^2} orbitals.

d_{z^2} orbitals within the trilayer unit, and an effective two-orbital description may be enough to describe the low-energy physics for both $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ and $\text{La}_3\text{Ni}_2\text{O}_7$. The metallization of the inter-layer σ -bonding bands recalls the emergence of the conventional high-temperature superconductivity in MgB_2 [44] and hydrides [6–8]. Therefore, the electronic structure characteristics of $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ may lie between those of $\text{La}_4\text{Ni}_3\text{O}_{10}$ and $\text{La}_3\text{Ni}_2\text{O}_7$.

Furthermore, the trilayer $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ superconductors also share the similar electronic structure and Fermi surface topology with multilayer high- T_c cuprate superconductors [45,46], such as $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ ($T_c \sim 93$ K), $\text{HgBa}_2\text{CaCu}_2\text{O}_{6+\delta}$ ($T_c \sim 120$ K), and $\text{Tl}_2\text{Ba}_2\text{CaCu}_2\text{O}_{8+\delta}$ ($T_c \sim 110$ K). In these multi-layer cuprates, we can clearly find that two similar active electronic bands near the Fermi level originate from the bonding and anti-bonding $d_{x^2-y^2}$ orbital bands from the outer layers, while the inner layer, if it exists, is not metallic. In particular, the van Hove singularity is also exhibited around the X point. Such similitude between $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ and multi-layer high- T_c cuprates could make $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ another candidate of superconductivity with unconventional pairing symmetry.

Note added: While preparing this paper, we also noted three related studies that reported resistance measurements under high pressure on $\text{Pr}_4\text{Ni}_3\text{O}_{10}$ polycrystalline and single crystal samples [47–50].

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Conflict of interest The authors declare that they have no conflict of interest.

Supporting Information

The supporting information is available online at <http://phys.scichina.com> and <https://link.springer.com>. The supporting materials are published as submitted, without typesetting or editing. The responsibility for scientific accuracy and content remains entirely with the authors.

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